Modal structure, directional and wavelength jumps of integrated semiconductor ring lasers: Experiment and theory

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(Received 18 June 2008; accepted 6 November 2008; published online 24 December 2008)

We have experimentally and theoretically analyzed the modal properties of semiconductor ring lasers and the wavelength jumps that occur in connection with directional switching above the threshold. © 2008 American Institute of Physics. [DOI: 10.1063/1.3052601]

For many years, semiconductor ring lasers (SRLs) have attracted interest for their potential in the fabrication of microcavity lasers and densely integrated photonics circuits. It has recently been realized that the coexistence of two counterpropagating modes in the same gain medium leads to a large variety of operating regimes and dynamics that are profoundly different from those of Fabry–Perot lasers. One of the most interesting properties is the fast directional bistability that could be harnessed for all-optical memories and signal processing. Besides their switching characteristics, SRLs show several unexpected behaviors such as hysteresis in the lasing direction and atypical lasing mode selection rules. In particular, when current or temperature are changed, the lasing mode does not hop between consecutive cavity modes but exhibits sudden jumps between several cavity modes only when the lasing direction reverses. This characteristic strongly enhances the stability of the lasing wavelength against changes in the operating conditions.

In this letter we report on the measurement of the transfer function of SRL devices, which provides us with a map of the cavity resonances and the emission wavelength of the SRLs when biased above the threshold. The transfer function can be theoretically explained by considering the perturbation induced by the light-extraction sections, which induces symmetry breaking in the resonant cavity and modulation of the cavity losses. For the geometry considered, the cavity losses have a wavelength periodicity that corresponds to the cavity losses. The power collected at port 3 as the input wavelength is scanned possesses a doublet structure, with the splitting between the longitudinal modes spaced by 0.4 nm. The peak heights show the expected profile defined by the wavelength-dependent gain spectrum in the structure and an additional modulation that occurs every three longitudinal modes.

Measurements on different devices show that the longitudinal modes possess a doublet structure, with the splitting between the two subpeaks varying from 1 to 4 GHz. In addition, for a particular device, the splitting between the subpeaks usually displays a modulation that corresponds to the structure and an additional modulation that occurs every three longitudinal modes.

FIG. 1. (Color online) Optical micrograph of a 300 μm radius ring laser with the corresponding measurement setup.

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with the additional modulation in the longitudinal mode spectrum described above. Figure 3 shows the measured doublet splitting for another device, which displays a modulation that also corresponds to a periodicity of roughly three mode spacings.

The power collected at port 4 (negative peaks in Fig. 2) presents a similar structure with the same periodicity, but instead of displaying peaks above a spontaneous-emission noise background, it shows dips on such a background. It is worth remarking that the depth of the dips strongly depends on the bias current in the SRL cavity. Indeed, due to the device layout, and facet reflectivities have been adjusted to match the experimental results.

The experimental results below the threshold can be explained by computing the transfer matrix of the complete SRL structure.\(^8\) We assume that the two couplers are identical, lossless, and with a residual reflectivity due to their pointlike character. Small reflectivity from output facets 1 and 2 is included, but not from facet 3 or 4 since the corresponding output waveguides are reverse biased. From this analysis, the roundtrip condition for the SRL modes in a resonator with equal arms of length \(L/2\) can be formulated as

\[ e^{2iqL} - ae^{iqL} + b = 0, \]

where \(q\) is the complex propagation constant. In Eq. (1), \(b = (r_d L - r_e L)^{-1} (r_d L - r_e L)^{-1}\) and \(a = (r_d L + r_e L + r_d L + r_e L) b\); \(t_{a(l)}\) and \(r_{a(l)}\) denote the frequency-dependent transmittivity and reflectivity of the upper (lower) coupler for CW waves, and primed symbols denote the same magnitudes for CCW waves. Defining \(Q_\pm = a/2 \pm [(a/2)^2 - b]^{1/2}\), the modes are given by

\[ q_m^\pm L = 2 \pi m - i \ln Q_\pm. \]

The light-extraction section breaks the circular symmetry of the SRL,\(^9\) destroying the pure CW and CCW states at \(q_m^\pm = 2 \pi m\). Two branches of solutions emerge due to the term \(-i \ln Q_\pm\), which correspond to the experimentally observed doublets. Their splitting, normalized to the free-spectral range of the SRL, is thus given by

\[ \Delta = \frac{1}{2 \pi} \left\{ \text{Im} \left[ \ln \left( \frac{Q_-}{Q_+} \right) \right] - \alpha \text{Re} \left[ \ln \left( \frac{Q_-}{Q_+} \right) \right] \right\}, \]

\(\alpha\) being the linewidth enhancement factor.

The theoretical results for the power at port 3 are in good agreement with the results shown in Fig. 2, provided that a small amount of gain in the SRL is included (see Fig. 6). In these calculations, the section lengths have been taken from the device layout, and facet reflectivities have been adjusted to match the experimental results.

The results for the transfer matrix to port 4 show similar trends, and the transfer matrix analysis does not lead to dips on a spontaneous-emission noise background. The reason is that the transfer matrix analysis does not include spontaneous-emission noise in the SRL cavity. Indeed, due to the (slight) gain in the SRL, the power collected at ports 3.
and 4 in the absence of external light is the power due to spontaneous emission in the SRL, including amplification and attenuation in the path. In the absence of any reflecting element, light injected into the SRL through port 1 would reach port 3 only after being amplified or attenuated along the path, and no injected light would reach port 4; however, the power at port 4 would be reduced because of amplified spontaneous-emission (ASE) suppression under light injection, thus leading to dips onto the ASE background. It is worth remarking that this effect provides us with a precise way to measure the spectral dependence of the transparency current.

In the same way, we can compute the theoretical detuning for the device used in Figs. 3 and 5 (see Fig. 7). The modulation of the detuning at three mode spacings is apparent, arising from the residual reflectivity at the bends of the output waveguides. In addition, it presents a further slow modulation that arises from the finite effective length of the output couplers and their residual reflectivities.

Finally, the wavelength jumps of several modes above the threshold can be partially explained with the same analysis, although a full explanation of the above-threshold phenomenology requires considering nonlinear effects arising from, e.g., four-wave mixing and spatial and spectral hole burning. From Eqs. (1) and (3) we see that for $\alpha \approx 2 - 3$, the maximum frequency splitting of the doublets almost coincides with their maximum threshold difference, whose modulation for each branch is out of phase. Hence, when the gain spectrum redshifts due to Joule heating, the system will jump from the minimum on one branch to the following minimum on the other branch. For circular SRL, where $L = 2R$, this means a jump of $m = \text{int}[3\tau_R/\tau_{FP}]$ modes of the SRL, where $\tau_{FP}$ is the roundtrip time in the SRL (Fabry–Perot) cavity. Thus, for the device considered here, the modal jumps correspond to $m = 3$.

In summary, we have experimentally studied the modal structure of SRLs by measuring the transfer properties of the device below the threshold and the wavelength jumps that occur in connection with directional switching above the threshold. A transfer matrix analysis explains the measurements when ASE in the SRL cavity is accounted for. The residual reflectivities in the light-extraction sections determine the frequency splitting and threshold difference between the two branches of solutions. This effect, together with the redshift of the material gain, explains the amount of wavelength jumps displayed by the SRL above the threshold.

We acknowledge financial support from the IOLOS (034743) project funded by the European Union’s Sixth Framework Program (EU FP6-2005-IST-5), the PhoDeCC (TEC2006-10009/MIC) project funded by the Spanish Ministerio de Educación y Ciencia (MIC), the QULMI (PROGECIB-5A) project funded by the Spanish Govern Balear, and the TEC2006-13887-C05-03 project funded by the Spanish Ministerio de Educación y Ciencia.